

YG865C15R (20A)

(150V / 20A)

[0401]

High Voltage Schottky barrier diode

■ Major characteristics

Characteristics	YG865C15R	Units	Condition
V _{RRM}	150	V	
V _F	0.90	V	T _c =25°C MAX.
I _o	20	A	

■ Features

- Low V_F
- High Voltage
- Center tap connection

■ Applications

- High frequency operation
- DC-DC converters
- AC adapter

Maximum ratings and characteristics

- Absolute maximum ratings (at Tc=25°C Unless otherwise specified)

Item	Symbol	Conditions	Rating	Unit
Repetitive peak surge reverse voltage	V_{RSM}	tw=500ns, duty=1/40	150	V
Repetitive peak reverse voltage	V_{RRM}		150	V
Isolating voltage	V_{iso}	Terminals-to-Case, AC.1min	1500	V
Average output current	I_o	Square wave, duty=1/2 $T_c=101^{\circ}C$	20 *	A
Non-repetitive surge current **	I_{FSM}	Sine wave 10ms 1shot	150	A
Operating junction temperature	T_j		+150	$^{\circ}C$
Storage temperature	T_{stg}		-40 to +150	$^{\circ}C$

* Out put current of center tap full wave connection

****Rating per element**

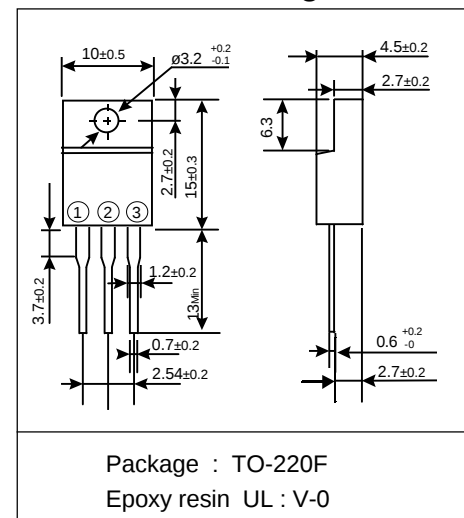
- Electrical characteristics (at Tc=25°C Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V_F	$I_{FM}=10A$	0.90	V
Reverse current	I_R	$V_R=V_{RRM}$	150	μA
Thermal resistance	$R_{th(j-c)}$	Junction to case	1.75	$^{\circ}C/W$

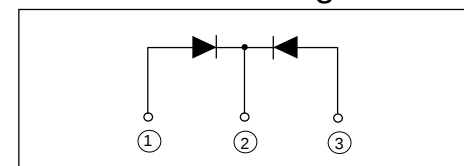
- Mechanical characteristics

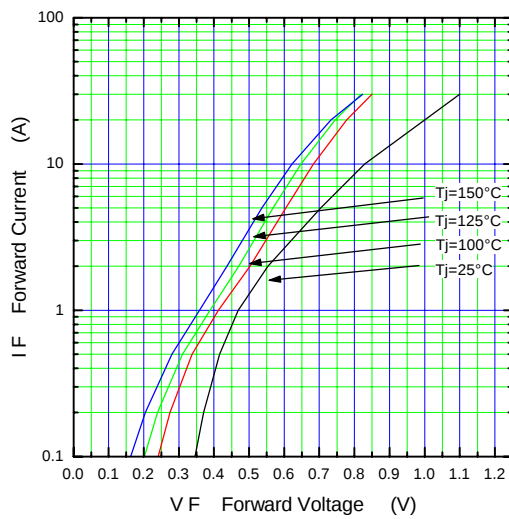
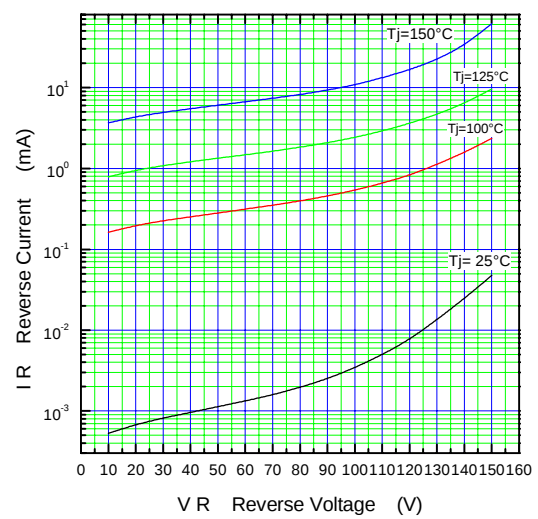
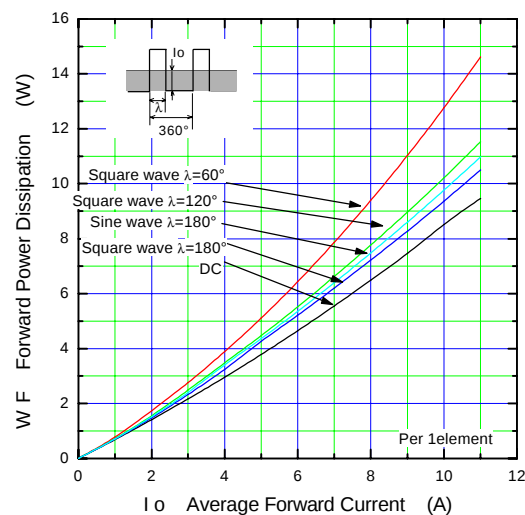
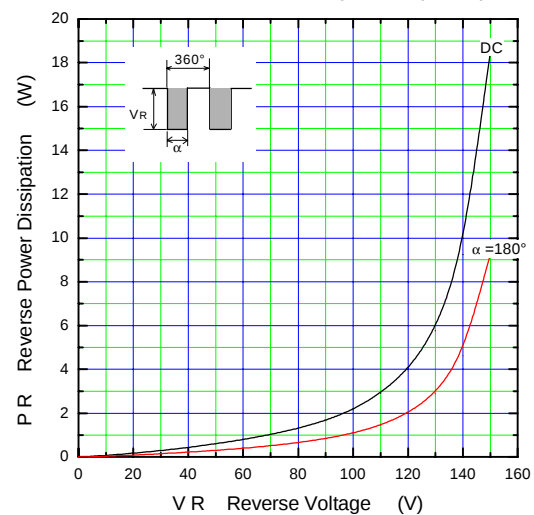
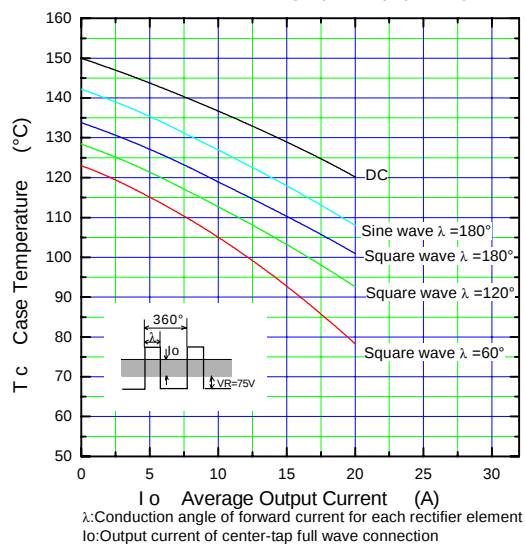
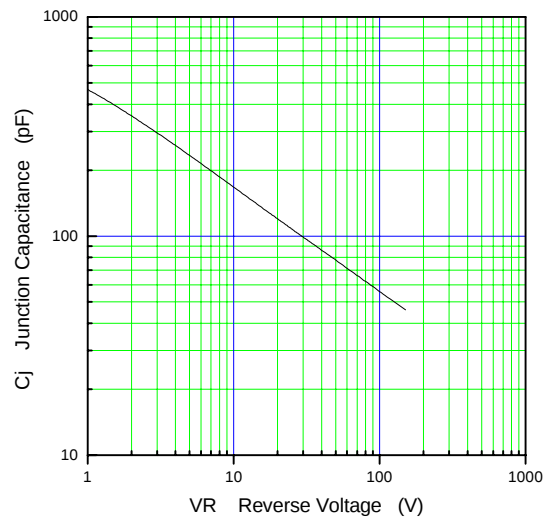
Mounting torque	Recommended torque	0.3 to 0.5	N·m
Approximate mass		2	g

■ Outline drawings, mm

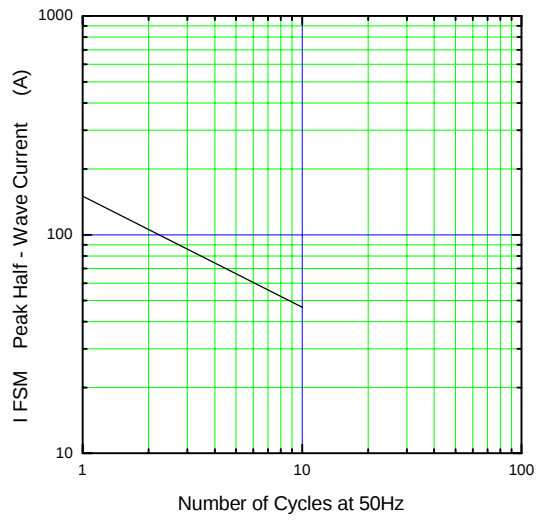


■ Connection diagram

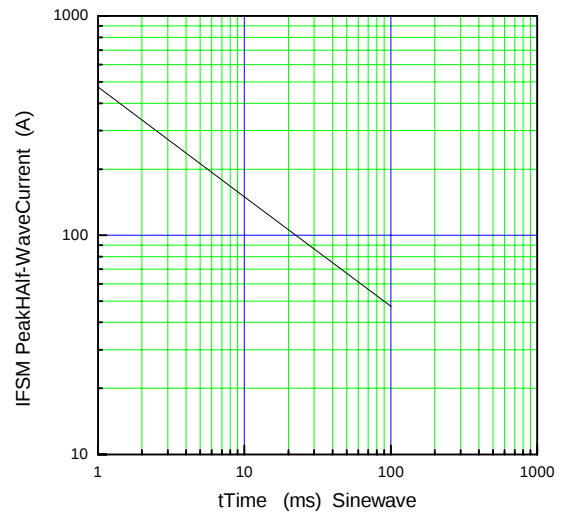


■ Characteristics**Forward Characteristic (typ.)****Reverse Characteristic (typ.)****Forward Power Dissipation (max.)****Reverse Power Dissipation (max.)****Current Derating (I_o - T_c) (max.)****Junction Capacitance Characteristic (max.)**

Surge Capability (max.)



Surge Current Ratings (max.)



Transient Thermal Impedance (max.)

